TOSHIBA BI-CMOS INTEGRATED CIRCUIT MULTICHIP

TB6512AF/AFG

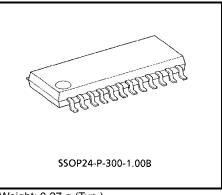
PWM CHOPPER TYPE BIPOLAR STEPPING MOTOR DRIVER

The TB6512AF/AFG is PWM chopper type sinusoidal micro step bipolar stepping motor driver.

Sinusoidal micro step operation is accomplished only a clock signal inputting by means of built-in hard ware.

FEATURES

- 1 chip bipolar sinusoidal micro step stepping motor driver.
- Output Current up to 150 mA
- PWM chopper type.
- Structured by high voltage Bi-CMOS process technology.
- Forward and reverse rotation are available.
- 1-2, 2W1-2 phase 1 or 2 clock drives are selectable.
- Package: SSOP24-P-300B
- Input Pull-Up Resistor equipped with RESET and ENABLE Terminal: R = 500 kΩ (Typ.)
- Output Monitor available with $\overline{\text{MO}}.\text{Io}(\overline{\text{MO}}) = \pm 2 \text{ mA MAX}.$
- Reset and Enable are available with RESET and ENABLE.



Weight: 0.27 g (Typ.)

TB6512AFG:

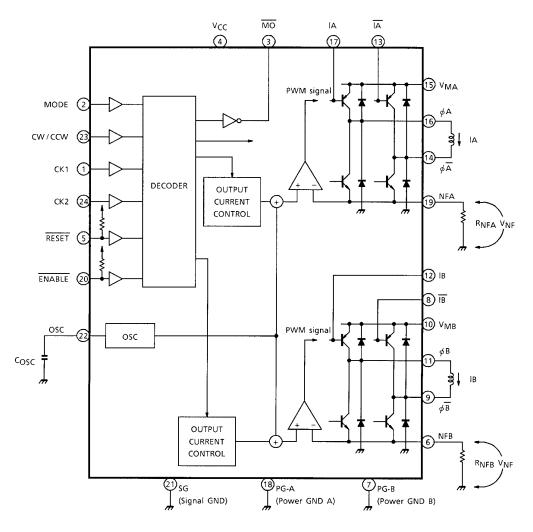
The TB6512AFG is a Pb-free product.

The following conditions apply to solderability:

*Solderability

- 1. Use of Sn-37Pb solder bath
 - *solder bath temperature = 230°C
 - *dipping time = 5 seconds
 - *number of times = once
 - *use of R-type flux
- 2. Use of Sn-3.0Ag-0.5Cu solder bath
 - *solder bath temperature = 245°C
 - *dipping time = 5 seconds
 - *the number of times = once
 - *use of R-type flux

BLOCK DIAGRAM



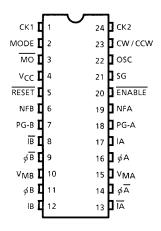
(5), (20) : Pull-up Resistor 500 k Ω (Typ.)



PIN FUNCTION

PIN No.	SYMBOL	FUNCTIONAL DESCRIPTION	
1	CK1	CLOCK Signal Input terminal	Truth table A
2	MODE	Excitation Mode Setting terminal	Truth table B
3	MO	Monitor Output terminal	
4	V _{CC}	Power voltage supply terminal for Logic	
5	RESET	Reset Signal Input terminal	Truth table A
6	NFB	B Channel current detective terminal	
7	PG-B	Power GND B terminal	
8	ΙΒ	Upper PNP Transistor Base terminal	
9	φĒ	Output B terminal	
10	V _{MB}	Power voltage supply terminal for Motor B	
11	φВ	Output B terminal	
12	IB	Upper PNP Transistor Base terminal	
13	ΙĀ	Upper PNP Transistor Base terminal	
14	φĀ	Output A terminal	
15	V _{MA}	Power voltage supply terminal for Motor A	
16	φΑ	Output A terminal	
17	IA	Upper side PNP Transistor Base terminal	
18	PG-A	Power GND A terminal	
19	NFA	A Channel current detective terminal	
20	ENABLE	ENABLE Signal Input terminal	Truth table A
21	SG	Signal GND terminal	
22	OSC	Internal Oscillation frequency detective terminal	
23	CW / CCW	Forward rotation / Reverse rotation signal Input	- Truth table A
24	CK2	Clock signal Input terminal	Truth table A

PIN CONNECTION



TRUTH TABLE A

	INPUT									
CK1	CK2	CW / CCW	RESET	ENABLE	MODE					
<u>_</u>	Н	L	Н	L	CW					
	L	L	Н	L	INHIBIT					
Н		L	Н	L	CCW					
L		L	Н	L	INHIBIT					
	Н	Н	Н	L	CCW					
	L	Н	Н	L	INHIBIT					
Н	7	Н	Н	L	CW					
L		Н	Н	L	INHIBIT					
Х	Х	Х	L	L	INITIAL					
Х	Х	Х	Х	Н	z					

Z : High impedance

X : Don't care

Note: Do not use INHIBIT mode.

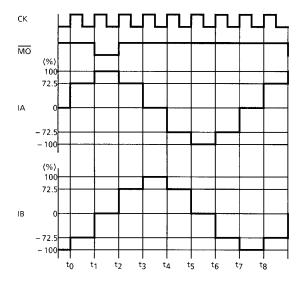
TRUTH TABLE B

INPUT	MODE
MODE	(EXCITATION)
L	1-2 phase
Н	2W1-2 phase

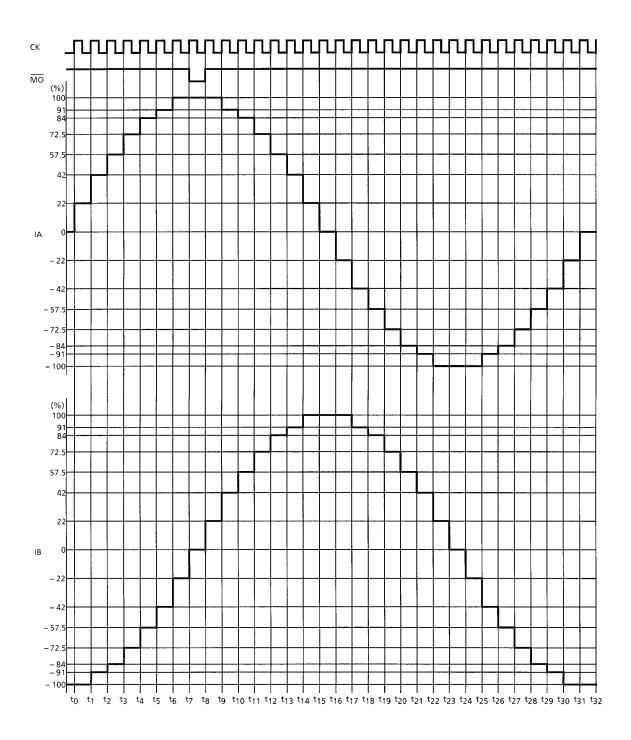
INITIAL MODE

EXCITATION MODE	I _{OUT} (A)	I _{OUT} (B)
1-2 phase	100%	0%
2W1-2 phase	100%	0%

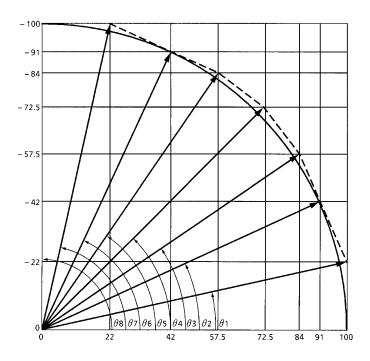
1-2 PHASE EXCITATION (MODE : L, CW mode)



2W1-2 PHASE EXCITATION (MODE: H, CW mode)

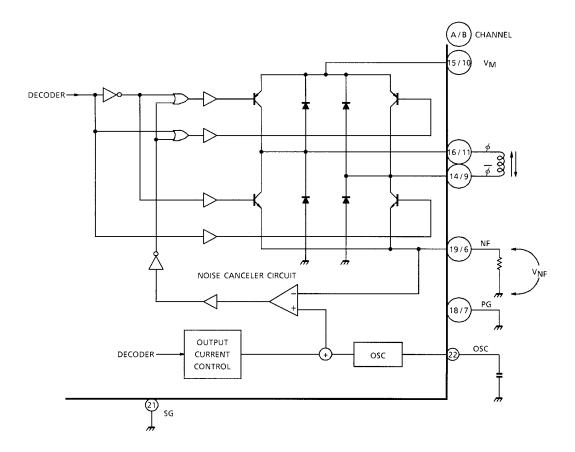


OUTPUT CURRENT VECTOR OR BIT (Normalize to 90 deg for each one step)

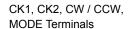


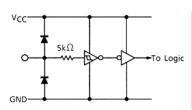
	DOTAT		VECT	ODIENCTU		
θ	ROTATI	ON ANGLE	VECTOR LENGTH			
0	IDEAL	TB6512AF/AFG	IDEAL	TB6512AF/AFG		
θ0	0°	0°	100	100.00		
θ1	11.25°	12.41°	100	102.39		
θ2	22.5°	27.78°	100	100.22		
θ3	33.75°	34.39°	100	101.80		
θ4	45°	45°	100	102.53		
θ5	56.25°	55.61°	100	101.81		
θ6	67.5°	65.22°	100	100.22		
θ7	78.75°	77.59°	100	102.39		
θ8	90°	90°	100	100.00		
		1-2 / 2	2W1-2 Phase			

OUTPUT CIRCUIT

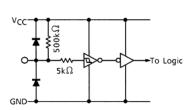


INPUT CIRCUIT

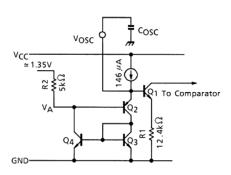




RESET, ENABLE Terminals



OSC Terminals



• OSC frequency calculation

Sawtooth OSC circuit consists of Q_1 through Q_4 and R_1 through R_4 .

Q2 is turned "off" when VOSC is less than the voltage of 2.5 V + VBE Q2 approximately equal to 2.05 V.

Vosc is increased by Cosc charging through R₁.

Q3 and Q4 are turned "on" when VOSC becomes 2.05 V (Higher level.)

Lower level of V(22) pin is equal to VBE Q2 + VSAT Q4 approximately equal to 1.4 V.

VOSC is calculated by following equation.

Assuming that $V_{OSC} = 1.4 \text{ V}$ (t = t₁) and = 2.05 (t = t₂)

 C_{OSC} is external capacitance connected to pin(22) and R_1 is on-chip 10 $k\Omega$ resistor.

Therefore, OSC frequency is calculated as follows.

$$t_1 = \frac{1.0 \times C_{OSC}}{146 \times 10^{-6}}$$

$$t_2 = \frac{2.05 \times C_{OSC}}{1000}$$

$$t_2 = \frac{2.05 \times C_{OSC}}{146 \times 10^{-6}}$$

$$\begin{split} f_{OSC} &= \frac{1}{t_2 - t_1} = \frac{146 \times 10^{-6}}{C_{OSC} \ (2.05 - 1.0)} \\ &= \frac{0.139}{C_{OSC}} (kHz) \ (C_{OSC} \ unit \ = \mu F) \end{split}$$

ENABLE AND RESET FUNCTION AND MO SIGNAL

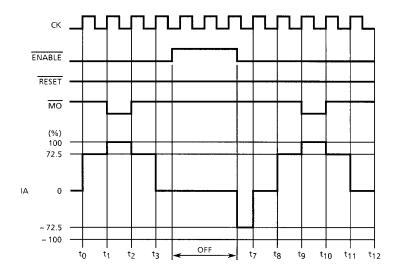


Fig.1. 1-2 phase drive mode (MODE: L)

 $\overline{\text{ENABLE}}$ signal disables only Output signal. Internal logic functions are proceeded by CK signal without regard to $\overline{\text{ENABLE}}$ signal.

Therefore, Output Current is initiated from the proceeded timing point of internal logic circuit, after release of disable mode.

Fig.1 shows the ENABLE functions, when the system is selected in 1-2 phase drive mode.

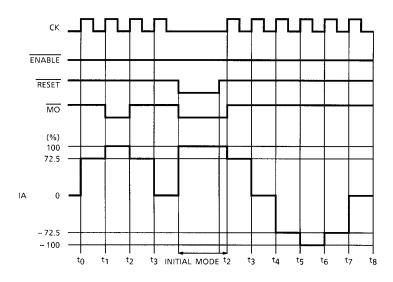


Fig.2. 1-2 phase drive mode (MODE : L)

As \overline{RESET} is low, the decoder is initialized and \overline{MO} is low.

After $\overline{\text{RESET}}$ is high, the motion is resumed from next clock as show in Fig.2.

MO (Monitor Output) signals is used as rotation and initial signal for stable. rotation checking.



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

CHARAC	TERISTIC	SYMBOL	RATING	UNIT
Supply Voltage		V _{CC}	5.5	V
Output Voltage		V _{M (opr.)}	4.0~10.0	V
Output Voltage		V _{M (MAX.)}	12.0	V
Output Current		I _{O (MAX.)}	120	A
	AVE.	I _{O(MO)}	±2	mA
Input Voltage		V _{IN}	~V _{CC}	V
Power Dissipation		P _D	0.83 (Note 1)	W
Fower Dissipation		۲۵	1.04 (Note 2)	VV
Operating Tempera	ature	T _{opr}	-30~85	°C
Storage Temperatu	ıre	T _{stg}	-55~150	°C
Feed Back Voltage	:	VI	1.0	V

Note 1: No heat sink

Note 2: With heat sink ($50 \times 50 \times 1.6$ mm Cu 10%)

RECOMMENDED OPERATING CONDITIONS (Ta = -30~85°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Supply Voltage	V _{CC} (opr.)		2.7	3.0	5.5	V
Output Voltage	V _M (opr.)		4.0	_	10.0	V
Output Current	lout		_	_	100	mA
Input Voltage	V _{IN}		_	_	Vcc	V
Clock Frequency	fclock		_	_	5	kHz
OSC Frequency	fosc		15	_	80	kHz



ELECTRICAL CHARACTERISTICS Unless otherwise specified, (Ta = 25°C, V_{CC} = 3 V, V_{M} = 5 V, L = 20 mH / R = 0.5 Ω)

CHARACTEF	RISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Input Voltage	High	VIN (H)		MODE, CW / CCW, ENABLE	V _{CC} ×0.7	_	V _{CC} +0.4	V	
input voltage	Low	V _{IN (L)}	1	CK1, CK2, RESET	GND -0.4	_	GND ×0.3	V	
Input Hysteresis Voltag	, ,		600	_	mV				
		I _{IN-1 (H)}		M1, M2, REF IN, V _{IN} = 5.0 V	_	_	100	nA	
Input Current		I _{IN-1 (L)}	1	RESET , V _{IN} = 0 V, ENABLE Internal pull-up resistor	3	6	12	μA	
		I _{IN-2 (L)}		V _{IN} = 0 V	_	_	100	nA	
Quiescent Current V _{CC}		I _{CC1}		Output open, RESET: H, ENABLE: L, (1-2 phase excitation)	_	5	9		
				Output open, RESET: H, ENABLE: L (2W1-2 phase excitation)	_	5	9	mA	
		I _{CC3}		RESET : L, ENABLE : H	_	1.3	_		
		I _{CC4}		RESET : H, ENABLE : H	Г:H, ENABLE:Н — 1.3				
Comparator Reference	Voltage	V _{NF}	3	R _{NF} = 2.5 Ω, C _{OSC} = 0.0033 μF	0.22	0.25	0.28	V	
Output Diffirencial		ΔVO	_	B / A, C_{OSC} = 0.0033 μF R_{NF} = 2.5 Ω	-10	_	10	%	
Maximum OSC Freque	ency	fosc (MAX.)	_		100	_	_	kHz	
Minimum OSC Freque	ncy	fosc (MIN.)	_		_	_	10	kHz	
OSC Frequency		fosc	_	C _{OSC} = 0.0033 μF	31	44	70	kHz	
Output Voltage		V _{OH} (MO)	_	I _{OH} = -40 μA	2.5		V _{CC}	V	
Output voltage		V _{OL} (MO)	_	I _{OL} = 40 μA	GND	0.1	0.5	v	



Output block

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TES	T CONDITION	MIN	TYP.	MAX	UNIT	
	Uppe	r Side	V _{SAT U1}		lour = 0.1	I -0.40 A		0.08	0.23	V
Output Saturation Voltage Diode Forward Voltage	n Lowe	r Side	V _{SAT L1}	1	1001 0.127		_	0.16	0.43	
	Uppe	r Side	V _{SAT U2}		lour = 0.00	6 ^		0.06	_	V
	Lowe	r Side	V _{SAT L2}		1001 - 0.00	0 A	I	0.10	_	
	Uppe	r Side	V _{F U1}	5	lour = 0.1	2 ^		1.13	1.8	V
Voltage	Lowe	r Side	V _{F L1}	CUIT	1.6	V				
Output Dark Current		I _{M1}		RESET	: "L" Level	-	_	50	μΑ	
(A+B Channels)	(A+B Channels)		I _{M2}	2	RESET	RESET : "H" Level		17	28	mA
NF Terminal Cu (1 Channels)	NF Terminal Current (1 Channels)		I _{NF}		RESET : "H" Level		1	2.5	7	IIIA
	2W1-2φ	1-2φ			θ = 0		1	100	_	
	2W1-2φ	_			θ = 1 / 8		_	100	_	
	2W1-2φ	_			θ = 2 / 8		86	91	96	
A-B Chopping Current	2W1-2φ	_	VECTOR	2	θ = 3 / 8		79	84	89	%
(Note)	2W1-2φ	1-2φ	VECTOR	3	θ = 4 / 8	$C_{OSC} = 0.0033 \mu F$	67.5	72.5	77.5	
	2W1-2φ	_			θ = 5 / 8		52.5	57.5	62.5	
	2W1-2φ	_			θ = 6 / 8		37	42	47	
	2W1-2φ	_			θ = 7 / 8		17	22	27	

Note: Maximum current ($\theta = 0$): 100%

 $\begin{array}{lll} 2W1-2\phi:\; 2W1,\; 2\; phase\; excitation\; mode\\ W1-2\phi\;\; :\;\; W1,\; 2\; phase\; excitation\; mode\\ 1-2\phi\;\; :\;\; 1,\; 2\; phase\; excitation\; mode \end{array}$



ELECTRICAL CHARACTERISTICS Unless otherwise specified, (Ta = 25°C, V_{CC} = 3 V, V_{M} = 5 V, L = 20mH / R = 0.5 Ω)

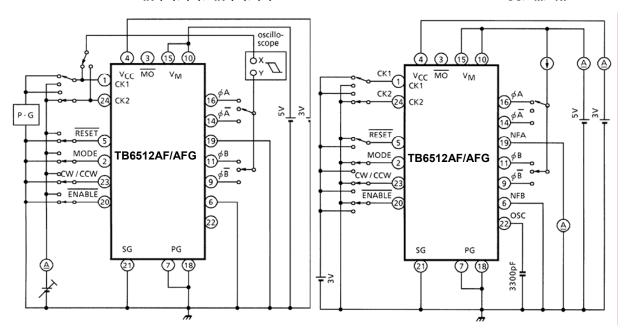
CHARACTERISTIC			SYMBOL	TEST CIR- CUIT	TES	T COI	NDITION	MIN	TYP.	MAX	UNIT	
	2W1-2φ	1-2φ			θ = 0			_	100	_		
	2W1-2φ	_			θ = 1 / 8			_	100	_		
	2W1-2φ	_			θ = 2 / 8			_	91.1	_		
A-B Chopping Current	2W1-2φ	_	VECTOR	3	θ = 3 / 8		= 3.3 Ω _C = 0.0033 μF	_	83.6	_	%	
(Note)	2W1-2φ	1-2φ	VECTOR	3	θ = 4 / 8	L = 5	$mH/R = 50 \Omega$	_	72.6	_	/0	
	2W1-2φ	_			θ = 5 / 8			_	60.0	_		
	2W1-2φ	_			θ = 6 / 8				44.5	_		
	2W1-2φ	_			θ = 7 / 8			_	24.3	_		
· ·				Δθ = 0 / 8-	-1/8			0	_			
					Δθ = 1 / 8-	-2/8	=	10	22.5	35		
					Δθ = 2 / 8-	θ = 2 / 8-3 / 8		5	17.5	30	mV	
Reference Volta	ge		ΔV_{NF}		$\Delta\theta = 3 / 8 - 4 / 8$ Cosc			16.25	28.75	41.25		
					Δθ = 4 / 8-	θ = 4 / 8-5 / 8 = 0.0033 μF	25	37.5	50			
					Δθ = 5 / 8-6 / 8		26.25	38.75	51.25			
					Δθ = 6 / 8-	-7 / 8		37.5	50	62.5		
			t _r		R _L = 2 Ω,	R _L = 2 Ω, V _{NF} = 0 V, C _L = 15		1	0.3	_		
			t _f		pF		_	2.2	_			
			t _{pLH}		CK ~ Output			_	1.5	_	1	
			t _{pHL}				_	2.7	_	1		
Output Tr Switch	ina Charaol	oriotico	t _{pLH}	7	OSC ~ Output			_	5.4	_		
Output 11 Switch	iiig Characi	ensucs	t _{pHL}] ′	030 ~ 00	ιραι		_	6.3	_	- µs -	
			t _{pLH}		RESET ~	Outou	+	_	2.0	_		
					KESE1 ~	Outpu	ι	_	2.5	_		
]	ENABLE	~ Outo	u it	1	5.0	_		
			t _{pHL}		ENABLE ~ Output		<u></u>	ı	6.0	_		
Output Leakage	Upper	Side	Іон	6	V _M = 12 V			_	_	50	μA	
Current	Upper	Side	I _{OL}		vM - 12 v			_	_	50	μΑ	

Note: Maximum current ($\theta = 0$): 100%

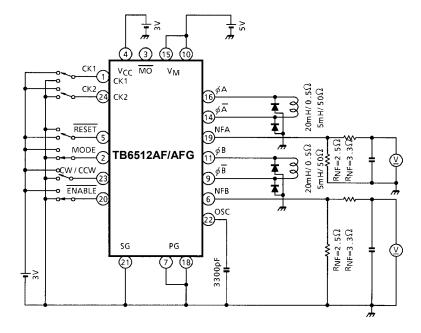
 $\begin{array}{lll} 2W1-2\phi:\; 2W1,\; 2\; phase\; excitation\; mode\\ W1-2\phi\;\; :\;\; W1,\; 2\; phase\; excitation\; mode\\ 1-2\phi\;\; :\;\; 1,2\; phase\; excitation\; mode \end{array}$

TEST CIRCUIT 1: V_{IN} (H), (L), I_{IN} (H), (L)

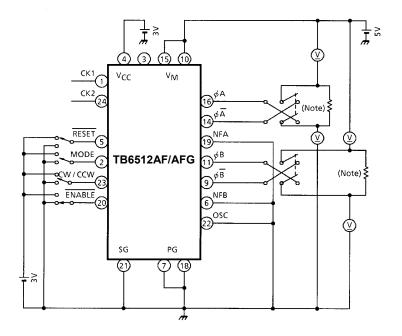
TEST CIRCUIT 2: I_{CC}, I_M, I_{NF}



TEST CIRCUIT 3: VNF

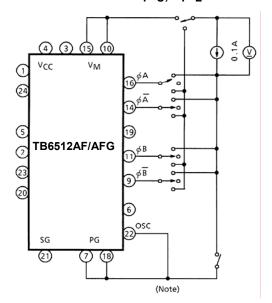


TEST CIRCUIT 4 : $V_{CE\;(SAT)}$ Upper, lower

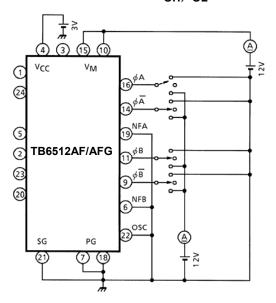


Note: Calibrate Output Current becomes 0.06 A (or 0.10 A) with this resistor.

TEST CIRCUIT 5: VF-U, VF-L



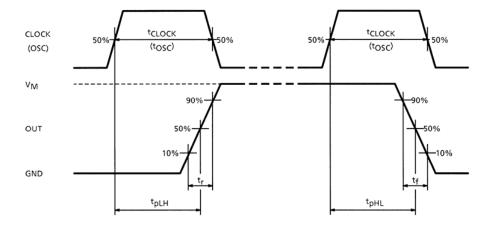
TEST CIRCUIT 6: IOH, IOL

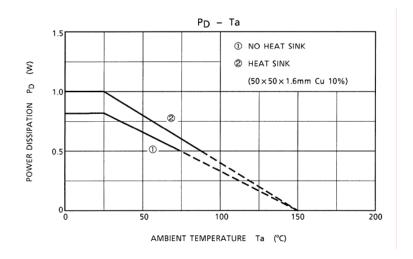


Note: Not to take a GND with any non-connecting Pins.

AC ELECTRICAL, CHARACTERICAL

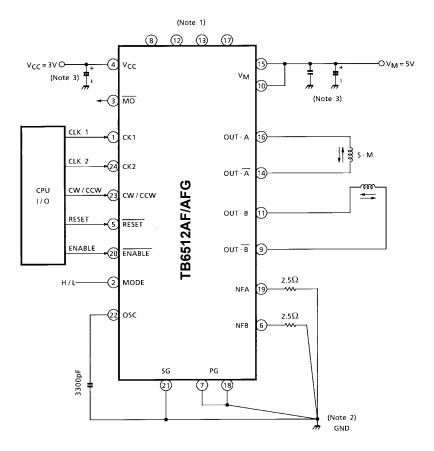
CK (OSC) - OUT





TB6512AF/AFG

APPLICATION CIRCUIT

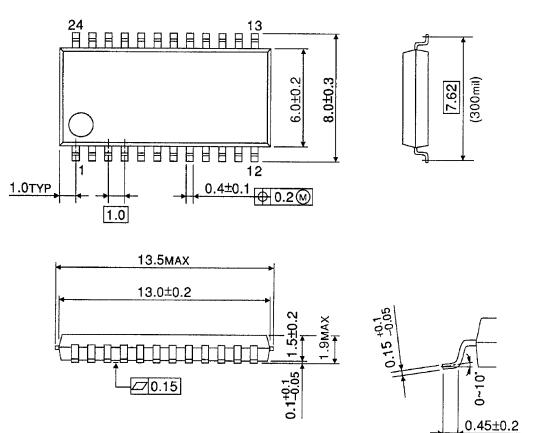


- Note 1: (8), (12), (13), (17) pin : open
- Note 2: GND pattern to be laid out at one point in order to prevent common impedance.
- Note 3: Capacitor for noise suppression to be connected between the Power Supply (V_{CC} , V_{M}) and GND to stabilize the operation.
- Note 4: Utmost care is necessary in the design of the output, V_{CC} , V_{M} , and GND lines since the IC may be destroyed by short-circuiting between outputs, air contamination faults, or faults due to improper grounding, or by short-circuiting between contiguous pins.

PACKAGE DIMENSIONS

SSOP24-P-300-1.00B

Unit: mm



Weight: 0.27 g (Typ.)

Notes on Contents

1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

3. Timing Charts

Timing charts may be simplified for explanatory purposes.

4. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

IC Usage Considerations Notes on handling of ICs

injury, smoke or ignition.

- [1] The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

 Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- [2] Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- [3] If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.

 Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause
- [4] Do not insert devices in the wrong orientation or incorrectly.

Make sure that the positive and negative terminals of power supplies are connected properly.

Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.

Points to remember on handling of ICs

(1) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (T_J) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

(2) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

RESTRICTIONS ON PRODUCT USE

060116EBA

- The information contained herein is subject to change without notice. 021023_D
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor
 devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical
 stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety
 in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such
 TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as
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